Constitutive and Failure Behavior of SnAgCu Solder Joints

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Constitutive and failure descriptions of SnAgCu solder alloys are of great interest at the present. Commonly, constitutive models that have been successfully used in the past for Sn-Pb solders are used to describe the behavior of SnAgCu solder alloys. Two issues in the characterization of lead-free solders demand careful attention: (i) Lead-free solders show significantly different creep strain evolution with time, stress and temperature and (ii) The building of valid constitutive models from test data derived from tests on solder joints must de-convolute the effects of joint geometry and its influence on stress heterogeneity. In the first part of the talk I will review the common approaches to modeling solder behavior, along with their limitations and then describe our efforts in developing constitutive models of SnAgCu solders that are valid across a wide range of strain rates.

The problem of solder joint fatigue is essentially one of fatigue crack growth. However, there is little work that has been done to arrive at fatigue life estimations by means of tracking of the crack front and its growth. Common fatigue life models such as the Coffin-Manson rule are empirical and therefore, limited in their applicability and in the insight they provide. There are several challenges to employing a fracture mechanics approach to accurately track the growth of a fatigue crack in a solder joint. Key among these, are the facts that the problem involves large-scale yielding, viscoplastic solder behavior and complex geometries. In the second part of the talk, I will describe the various approaches to modeling solder joint fatigue and present our efforts at developing Cohesive Zone Model inspired approaches to predicting crack propagation at solder interfaces.

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Predicted Life Depends on...



Reliability Modeling Strategy



Constitutive Behavior of SnAgCu Solder Alloys – Part I



Strain Rate Regimes



Low Strain Rate Behavior



Experimental Set Up







Environmental Chamber Controller EC 1615 (Range -70 C to 250 C)



Double lap shear setup with capacitance sensor probe



Test Specimen Alumina coupons Sn3.8Ag0.7Cu solder joints

Impact of Displacement Control

- Need to resolve displacements ~10 nm
- Crosshead control results in load train compliance
- **Displacement control** established by a **closed loop** with capacitance sensor and Instron crosshead displacement



Monotonic Behavior

- Response depends on strain rate
 - Materials "stronger" at higher strain rate
- No clearly identifiable proportional limit in SnAgCu alloys
- Elastic, nearly perfectly plastic behavior





Creep Behavior

- Nature of response depends on stress level and temperature
 - Typically occurs when $\frac{T}{T_m} \ge 0.3$
 - Operating temperature is a high fraction of melting point. At 100° C for example
 - $\frac{T}{T_m} \ge 0.7$ for Sn3.8 Ag0.7Cu solder
- Historically, in SnPb alloys, only secondary creep considered





Zener Hollomon Plots



Strain rate and temperature effects equivalent!



Monotonic Vs. Creep Data



Similar results for SAC387 and SAC105

Monotonic and creep data consistent!



Primary creep



Clech (2005)

Significant primary creep duration!



Comparison of SnAgCu Alloys



- SAC305 and SAC387 behave similarly
- SAC105 softer than SAC305 and SAC387



Comparison with SnPb Alloys



- SAC305 and SAC387 better creep resistance over load range
- SAC105 creep resistance better only at lower loads



High Strain Rate Behavior



Compression Test Setup and Specimen

Intermediate Strain Rate: 0.001s⁻¹ to 31s⁻¹





Test Specimen: 5mm x ø5mm

Alloy: Sn3.8Ag0.7Cu



Split Hopkinson Bar Test Setup

High Strain Rate: 175s⁻¹ and 500s⁻¹

Striker



Dynamic Test Setup at McDonnel Douglas Composite Material Laboratory at Purdue University (W. Chen)

High speed digital camera (1024x1024 pixel resolution; 2,000,000 frames per second)





Test Methods For High Strain Rate Characterization







Test Specifications:

- Cutting speed: 10mm/sec
- Depth of cut: 250 micrometer
- Rake angle of the tool: 0 degree
- Image frame rate: 250 frames/sec



Response of Sn3.8Ag0.7Cu Solder

Effective Strain Rate

Forces Acting on Cutting Tool



Summary of Test Data





Model Fit to Data





Implications of Rate-Dependent Behavior



Failure Observations



Thermal Cycling (HDPUG)



Drop Test Ball Shear Test



10mm/s – bulk fracture



1000mm/s - partial fracture



10,000mm/s – interface fracture (Kaulfersch 2007)

•Bulk solder, interface failure, or a combination?

•Function of strain rate dependence of IMC, solder, and interface





Localization at High Strain Rate





Fracture Simulations using Cohesive Zone Model



250 Stress (MPa) 200 Bulk 150 Failure Maximum TSL 100 Interface Failure 50 0 1 10 100 1000 10000 100000 1000000 Strain Rate (s-1) Interface failure Bulk failure

Bilinear traction separation law used in the cohesive zone elements along the solder interface; σ_{max} is varied, cohesive energy kept constant



Fatigue Fracture in Solder Joints – Part II



Crack Growth in Solder Joints







Courtesy HDPUG

QFN, 0.5mm pitch, 64 I/Os, 4mm square Accelerated thermal cycling (-40 to 125°C)









Courtesy TI

Introduction

- Failure models typically empirical
 - Geometry, package construction dependent
 - Fracture not modeled explicitly
- Few non-empirical failure models
 A new model for hierarchical fracture processes



Fatigue Failure Modeling Approaches

Empirical	Damage Mechanics	Paris Law
$N_f = \left(\frac{C}{\Delta \varepsilon^p}\right)^{\frac{1}{m}}$	$N_f = \frac{1 - (1 - D_f)^{k+1}}{(k+1)L}$	$\frac{da}{dN} = C_1 (\Delta K)^m$
 ✓ Ease of use ★ Constant rate of damage assumed ★ Physics and crack growth not described 	 ✓ Allows for incorporation of physics of failure ★ Computationally expensive for all cycles ★ Crack growth not described 	 ✓ Describes crack growth ✓ Demonstrated validity × Not valid for large plasticity or large cracks × Limiting assumptions (self-similar crack growth, constant-amplitude loading)



Towashiraporn et. al. (2004)

Limitations of Fracture Mechanics

- Linear Elastic Fracture Mechanics (G, K)
 - Linear elastic materials or small-scale yielding
- Elastic-Plastic Fracture Mechanics (J-integral, CTOA, CTOD)

Applicable for deformation plasticity, impractical measures

• Paris Law
$$\frac{da}{dN} = C_1 (\Delta K)^m$$
 or $\frac{da}{dN} = C_2 (\Delta J)^n$

– Self-similar crack growth, small-scale yielding



Application to SnAgCu Solder Joints

Chip Scale Package (1.56 mm) Quad Flat Noleads Package (4 mm)





Solder

Package

PCB PAD





Crack Growth in CSP Solder Joints



Test Specimen and Test Conditions

- 50 I/O chip scale packages
- SAC387 solder
 - 0.3 mm pitch
 - 165 µm pad diameter
 - 134 µm standoff height
- Silicon substrate 3.5x3.5x0.3 mm
- Accelerated thermal cycling
- Failure analysis every 240 cycles





Failure Analysis Technique

- Failure analysis performed every 240 cycles
 - Tape wrapped around PCB
 - Liquid nitrogen used to embrittle solder joints
 - Mechanically pried
 - No dye marker
- Differentiated fracture morphology
- Optical microscopy performed
 - ScionImage
 - Crack length
 - Crack area





Prying procedure used remove the component for visual observation of crack front growth

Observations of Crack Fronts





Crack front at 960 thermal cycles for the corner and mid-edge joints in a CSP package.



Progress of Crack







Geometry Dependence of Fatigue Crack Growth







Computational Procedure



Simulation of Fracture Progression



Test versus Simulation



Geometry Influence on Fracture Morphology

SDV4 (Avg: 75%) +1.000e+00 +9.500e-01 +9.000e-01 +4.775e-06

•UBM structure causes crack to briefly propagate into the bulk under interface before re-emerging



Comparison of Crack Progression



Crack Growth in QFN Solder Joints



Test Specimen and Test Conditions

- 48 0.5 mm pitch QFN packages
- SAC387 solder
 - 64 joints
 - Standoff height: 60µm
 - Landing pad: 0.233x0.725mm
- FR-4 board 93 mills
- Silicon die within 1 mm thick mold compound
- ATC conditions as shown
- Failure when electrical resistance is 10.6 Ohms





Test Results and Weibull Fit



Cumulative Failure Statistics			
0.1%	1.00%	63.20%	
275	406	884	

Weibull Reliability Parameters			
β	η	\mathbb{R}^2	
5.91	883.9	96.07	



Fatigue Crack Growth



- Multiple crack initiation locations
- •Strong influence of geometry on failure







Details of FE Model

- 1/8th geometry
- Solder material behavior
 - Time hardening creep
 - Rate independent plastic properties
- FR-4
 - Temperature dependent, anisotropic elastic properties
- Passivation layer
- 65,820 elements
 - Solder joints -5,655 elements
- Isothermal boundary conditions









Failure Progression





- Predicted life 806 cycles
- Furthest joint fails first





Comparison to Observed Trajectories



- •
- Fracture not at interface •





Summary



Accurate physical models can lead to accurate package-independent reliability **predictions**!



Related Journal Publications

- D. Bhate, G. Subbarayan, L. Nguyen, J. Zhao, D. Edwards, "Singularities at Solder Joint Interfaces and their Effects on Fracture Models," ASME Journal of Electronic Packaging, under review.
- X. Nie, D. Chan, D. Bhate, W. Chen, G. Subbarayan, and I. Dutta, "Intermediate and High-Strain Rate Behavior of Sn3.8Ag0.7Cu and Sn1.0Ag0.5Cu Solder Alloys: Constitutive Models and their Demonstration" IEEE Transactions on Components and Packaging Technologies.K. Mysore, G. Subbarayan, V. Gupta, R. Zhang, "Constitutive and Aging Behavior of Sn3.0Ag0.5Cu Solder Alloy," IEEE Transactions, Electronics Packaging Manufacturing, in press.
- D. Bhate, G. Subbarayan, J. Zhao, V. Gupta, and D. Edwards "Improved Solder Joint Fatigue Models through Reduced Geometry Dependence of Empirical Fits" ASME Transactions Journal of Electronic Packaging, in press.
- I. Dutta, P. Kumar, and G. Subbarayan, "Microstructural Coarsening in Sn-Ag Based Solders and Its Effects on Mechanical Properties," Journal of Metals (JOM), vol. 61, no. 6, pp. 29-38, TMS, 2009.
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- P. Towashiraporn, G. Subbarayan and C.S. Desai. "A Hybrid Model for Computationally Efficient Fatigue Fracture Simulations at Microelectronic Assembly Interfaces." International Journal of Solids and Structures, vol. 42, pp. 4468-4483, 2005.
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- P. Towashiraporn, G. Subbarayan, B. McIlvanie, B.C. Hunter, D. Love, and R. Sullivan. "The Effect of Model Building on the Accuracy of Fatigue Life Predictions in Electronic Packages." Microelectronics Reliability, vol. 44, no. 1, pp. 115-127, 2004.
- P. Towashiraporn, G. Subbarayan, B. McIlvanie, B.C. Hunter, D. Love, and R. Sullivan. "Predictive Reliability Models through Validated Correlation between Power Cycling and Thermal Cycling Accelerated Life Tests." Soldering and Surface Mount Technology, vol. 14, no. 3, pp. 51-60, 2002.



Recent Conference Publications

- D. Chan, X. Nie, D. Bhate, G. Subbarayan, W. Chen, and I. Dutta, "High Strain Rate Behavior of Sn3.8Ag0.7Cu Solder Alloys and Its Influence on the Fracture Location within Solder Joints," In proceedings of the ASME/Pacific Rim Technical Conference and Exhibition on Packaging and Integration of Electronic and Photonic Systems, MEMS, and NEMS (Interpack '09), July 19-23, San Franciso, CA, 2009, ASME, Paper number IPACK2009-89404, 2009.
- D. Chan, D. Bhate, G. Subbarayan, J. Zhao, D. Edwards, "Predicting Crack Growth and Fatigue Lives of QFN Solder Joints using a Multiscale Fracture Model," In proceedings of the ASME/Pacific Rim Technical Conference and Exhibition on Packaging and Integration of Electronic and Photonic Systems, MEMS, and NEMS (Interpack '09), July 19-23, San Franciso, CA, 2009, ASME, Paper number IPACK2009-89403, 2009.
- D. Chan, D. Bhate, G. Subbarayan, L. Nguyen, "Characterization of Crack Fronts in a WLCSP Package: Experiments and Models for Application of a Multiscale Fracture Theory," In proceedings of the ASME/Pacific Rim Technical Conference and Exhibition on Packaging and Integration of Electronic and Photonic Systems, MEMS, and NEMS (Interpack '09), July 19-23, San Franciso, CA, 2009, ASME, Paper number IPACK2009-89402, 2009.
- K. Mysore, S. Chavali, D. Chan, G. Subbarayan, I. Dutta, V. Gupta, D. Edwards, "Mechanistic Model for Aging Influenced Steady State Flow Behavior of Sn3.8Ag0.7Cu Solder Alloys," In proceedings of the ASME/Pacific Rim Technical Conference and Exhibition on Packaging and Integration of Electronic and Photonic Systems, MEMS, and NEMS (Interpack '09), July 19-23, San Franciso, CA, 2009, ASME, Paper number IPACK2009-89401.
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